

ON CHARACTERISTICS (Note 2)

$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	0.65	0.85	1.5	V
$\Delta V_{GS(th)} / \Delta T_J$	Gate Threshold Voltage Temperature Coefficient	$I_D = 250 \mu A$, Referenced to 25°C	-	-2.1	-	mV/°C
$R_{DS(on)}$	Static Drain-Source On-Resistance	$V_{DS} = 4.5 V$, $I_D = 0.22 A$	-	2.6	4	Ω
		$V_{DS} = 4.5 V$, $I_D = 0.22 A$, $T_J = 125^\circ C$	-	5.3	7	
		$V_{DS} = 2.7 V$, $I_D = 0.19 A$	-	3.7	5	
$I_{D(on)}$	On-State Drain Current	$V_{GS} = 4.5 V$, $V_{DS} = 5 V$	0.22	-	-	A
g_{FS}	Forward Transconductance	$V_{DS} = 5 V$, $I_D = 0.22 A$	-	0.2	-	S

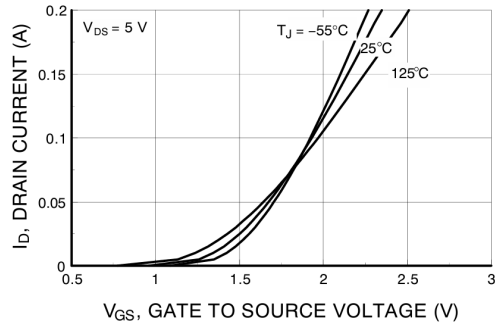
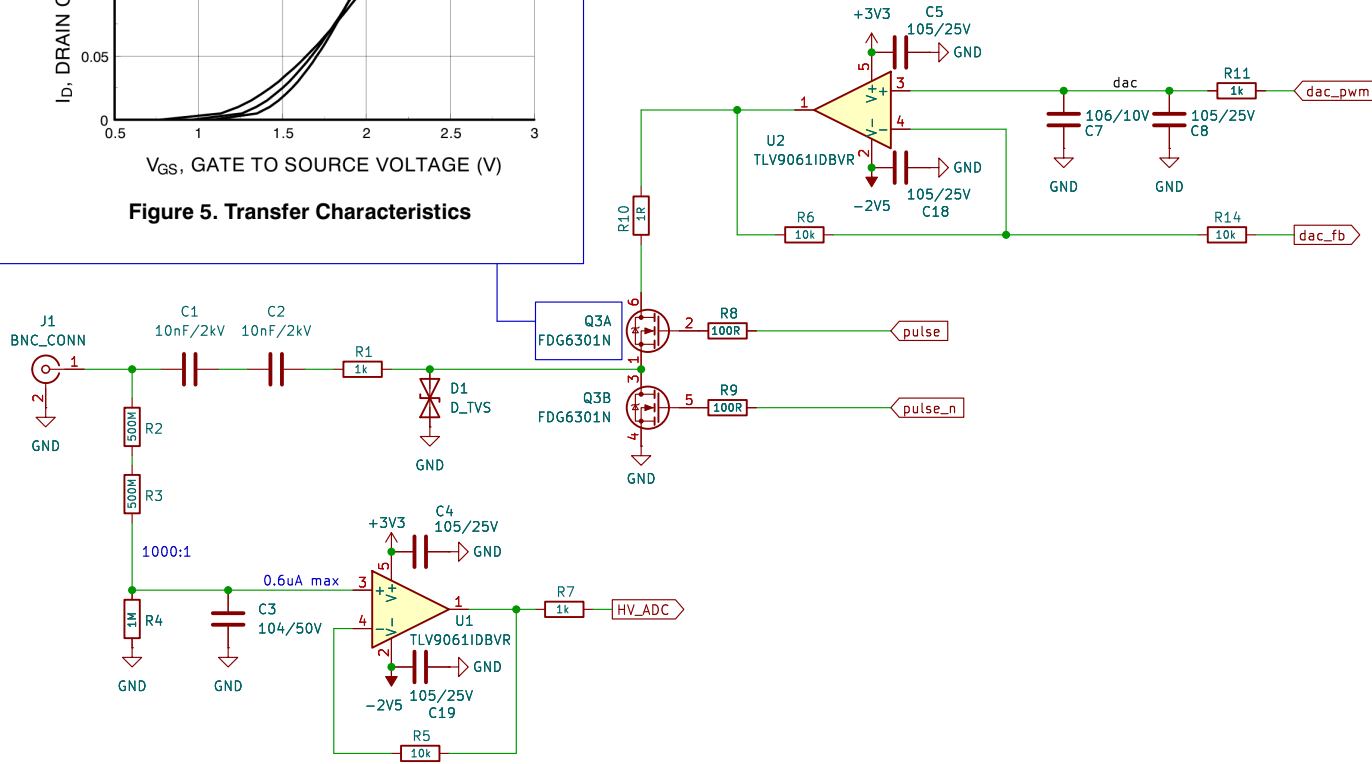


Figure 5. Transfer Characteristics



POWER



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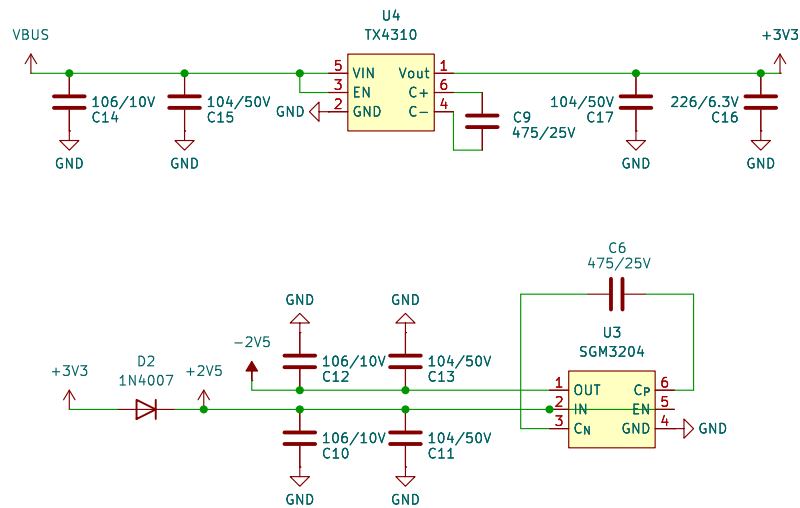
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